

MOTOROLA SEMICONDUCTOR TECHNICAL DATA

MC33272 MC33274

SINGLE SUPPLY, HIGH SLEW RATE LOW INPUT OFFSET VOLTAGE, BIPOLAR OPERATIONAL AMPLIFIERS

The MC33272/4 series of monolithic operational amplifiers are quality fabricated with innovative Bipolar design concepts. This dual and quad operational amplifier series incorporates Bipolar inputs along with a patented Zip-R-Trim element for input offset voltage reduction. The MC33272/4 series of operational amplifiers exhibits a low input offset voltage and high gain bandwidth product. Dual-doublet frequency compensation is used to increase the slew rate while maintaining low input noise characteristics. Its all NPN output stage exhibits no deadband crossover distortion, large output voltage swing, and an excellent phase and gain margin. It also provides a low open-loop high frequency output impedance with symmetrical source and sink AC frequency performance.

The MC33272/4 series is specified over -40°C to $+85^{\circ}\text{C}$ and is available in the plastic DIP and SOIC surface mount packages (P and D suffixes).

- Input Offset Voltage Trimmed to $100\ \mu\text{V}$ (Typ)
- Low Input Bias Current: $300\ \text{nA}$
- Low Input Offset Current: $3.0\ \text{nA}$
- High Input Resistance: $16\ \text{M}\Omega$
- Low Noise: $18\ \text{nV}/\sqrt{\text{Hz}}$ (ω 1.0 kHz)
- High Gain Bandwidth Product: $24\ \text{MHz}$ (ω 100 kHz)
- High Slew Rate: $10\ \text{V}/\mu\text{s}$
- Power Bandwidth: $160\ \text{kHz}$
- Excellent Frequency Stability
- Unity Gain Stable: w/ Capacitance Loads to $500\ \text{pF}$
- Large Output Voltage Swing: $+14.1\ \text{V}/-14.6\ \text{V}$
- Low Total Harmonic Distortion: 0.003%
- Power Supply Drain Current: $2.15\ \text{mA}$ per Amplifier
- Single or Split Supply Operation: $+3.0\ \text{V}$ to $+36\ \text{V}$ or $\pm 1.5\ \text{V}$ to $\pm 18\ \text{V}$

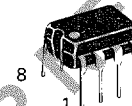
ORDERING INFORMATION

Op Amp Function	Device	Specified Ambient Temperature Range	Package
Dual	MC33272D	-40°C to $+85^{\circ}\text{C}$	SO-8
	MC33272P		Plastic DIP
Quad	MC33274D		SO-14
	MC33274P		Plastic DIP

HIGH PERFORMANCE OPERATIONAL AMPLIFIERS

SILICON MONOLITHIC
INTEGRATED CIRCUIT

MC33272

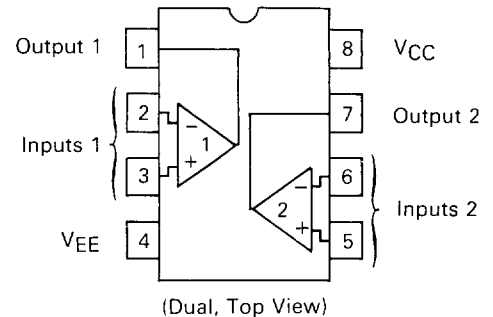


P SUFFIX
PLASTIC PACKAGE
CASE 626

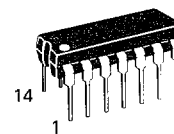


D SUFFIX
PLASTIC PACKAGE
CASE 751
(SO-8)

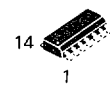
PIN ASSIGNMENTS



MC33274

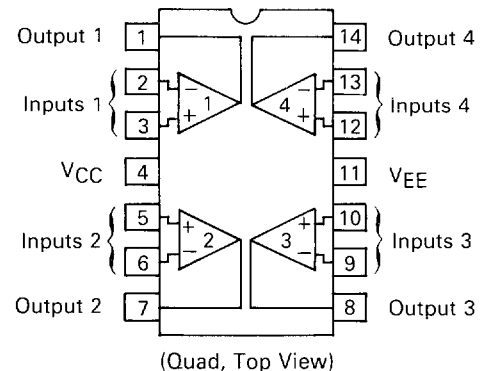


P SUFFIX
PLASTIC PACKAGE
CASE 646



D SUFFIX
PLASTIC PACKAGE
CASE 751A
(SO-14)

PIN ASSIGNMENTS



MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Supply Voltage	V_{CC} to V_{EE}	+36	V
Input Differential Voltage Range	V_{IDR}	(Note 1)	V
Input Voltage Range	V_{IR}	(Note 1)	V
Output Short Circuit Duration (Note 2)	t_S	Indefinite	Seconds
Maximum Junction Temperature	T_J	+150	°C
Storage Temperature	T_{stg}	-60 to +150	°C
Maximum Power Dissipation	P_D	(Note 2)	mW

NOTES:

- Either or both input voltages should not exceed V_{CC} or V_{EE} .
- Power dissipation must be considered to ensure maximum junction temperature (T_J) is not exceeded (see Figure 2).

DC ELECTRICAL CHARACTERISTICS ($V_{CC} = +15$ V, $V_{EE} = -15$ V, $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Figure	Symbol	Min	Typ	Max	Unit
Input Offset Voltage ($R_S = 10 \Omega$, $V_{CM} = 0$ V, $V_O = 0$ V) ($V_{CC} = +15$ V, $V_{EE} = -15$ V) $T_A = +25^\circ\text{C}$ $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$ ($V_{CC} = 5.0$ V, $V_{EE} = 0$) $T_A = +25^\circ\text{C}$	3	$ V_{IO} $	—	0.1	1.0	mV
Average Temperature Coefficient of Input Offset Voltage $R_S = 10 \Omega$, $V_{CM} = 0$ V, $V_O = 0$ V, $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$	3	$\Delta V_{IO}/\Delta T$	—	2.0	—	$\mu\text{V}/^\circ\text{C}$
Input Bias Current ($V_{CM} = 0$ V, $V_O = 0$ V) $T_A = +25^\circ\text{C}$ $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$	4, 5	I_{IB}	—	300	650	nA
Input Offset Current ($V_{CM} = 0$ V, $V_O = 0$ V) $T_A = +25^\circ\text{C}$ $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$		$ I_{IO} $	—	3.0	65	nA
Common Mode Input Voltage Range ($\Delta V_{IO} = 5.0$ mV, $V_O = 0$ V) $T_A = +25^\circ\text{C}$	6	V_{ICR}	V_{EE} to $(V_{CC} - 1.8)$			V
Large Signal Voltage Gain ($V_O = 0$ to 10 V, $R_L = 2.0$ k Ω) $T_A = +25^\circ\text{C}$ $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$	7	A_{VOL}	90	100	—	dB
Output Voltage Swing ($V_{ID} = \pm 1.0$ V) ($V_{CC} = +15$ V, $V_{EE} = -15$ V) $R_L = 2.0$ k Ω $R_L = 2.0$ k Ω $R_L = 10$ k Ω $R_L = 10$ k Ω ($V_{CC} = 5.0$ V, $V_{EE} = 0$ V) $R_L = 2.0$ k Ω $R_L = 2.0$ k Ω	8, 9, 12	V_{O+} V_{O-} V_{O+} V_{O-}	13.4 — 13.4 —	13.9 -13.9 14 -14.7	— -13.5 — -14.1	V
Common Mode Rejection ($V_{in} = +13.2$ V to -15 V)	13	CMR	90	100	—	dB
Power Supply Rejection $V_{CC}/V_{EE} = +15$ V/ -15 V, $+5.0$ V/ -15 V, $+15$ V/ -5.0 V	14, 15	PSR	90	105	—	dB
Output Short Circuit Current ($V_{ID} = 1.0$ V, Output to Ground) Source Sink	16	I_{SC}	+25 -25	+37 -37	— —	mA
Power Supply Current Per Amplifier ($V_O = 0$ V) ($V_{CC} = +15$ V, $V_{EE} = -15$ V) $T_A = +25^\circ\text{C}$ $T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$ ($V_{CC} = 5.0$ V, $V_{EE} = 0$ V) $T_A = +25^\circ\text{C}$	17	I_{CC}	— — —	2.15 — —	2.75 3.0 2.75	mA

AC ELECTRICAL CHARACTERISTICS ($V_{CC} = -15\text{ V}$, $V_{EE} = -15\text{ V}$, $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Figure	Symbol	Min	Typ	Max	Unit
Slew Rate ($V_{in} = -10\text{ V}$ to $+10\text{ V}$, $R_L = 2.0\text{ k}\Omega$, $C_L = 100\text{ pF}$, $A_V = +1.0$)	18, 33	SR	8.0	10	—	$\text{V}/\mu\text{s}$
Gain Bandwidth Product ($f = 100\text{ kHz}$)	19	GBW	17	24	—	MHz
AC Voltage Gain ($R_L = 2.0\text{ k}\Omega$, $V_O = 0\text{ V}$, $f = 20\text{ kHz}$)	20, 21, 22	A_{VO}	—	65	—	dB
Unity Gain Frequency (Open-Loop)		f_U	—	5.5	—	MHz
Gain Margin ($R_L = 2.0\text{ k}\Omega$, $C_L = 0\text{ pF}$)	23, 24, 26	A_m	—	12	—	dB
Phase Margin ($R_L = 2.0\text{ k}\Omega$, $C_L = 0\text{ pF}$)	23, 25, 26	ϕ_m	—	55	—	Deg
Channel Separation ($f = 20\text{ Hz}$ to 20 kHz)	27	CS	—	-120	—	dB
Power Bandwidth ($V_O = 20\text{ V}_{p-p}$, $R_L = 2.0\text{ k}\Omega$, $\text{THD} \leq 1.0\%$)		BWP	—	160	—	kHz
Total Harmonic Distortion ($R_L = 2.0\text{ k}\Omega$, $f = 20\text{ Hz}$ to 20 kHz , $V_O = 3.0\text{ V}_{\text{rms}}$, $A_V = +1.0$)	28	THD	—	0.003	—	%
Open-Loop Output Impedance ($V_O = 0\text{ V}$, $f = 6.0\text{ MHz}$)	29	$ Z_O $	—	35	—	Ω
Differential Input Resistance ($V_{CM} = 0\text{ V}$)		R_{IN}	—	16	—	$\text{M}\Omega$
Differential Input Capacitance ($V_{CM} = 0\text{ V}$)		C_{IN}	—	3.0	—	pF
Equivalent Input Noise Voltage ($R_S = 100\ \Omega$, $f = 1.0\text{ kHz}$)	30	e_n	—	18	—	$\text{nV}/\sqrt{\text{Hz}}$
Equivalent Input Noise Current ($f = 1.0\text{ kHz}$)	31	i_n	—	0.5	—	$\text{pA}/\sqrt{\text{Hz}}$

FIGURE 1 — EQUIVALENT CIRCUIT SCHEMATIC (EACH AMPLIFIER)

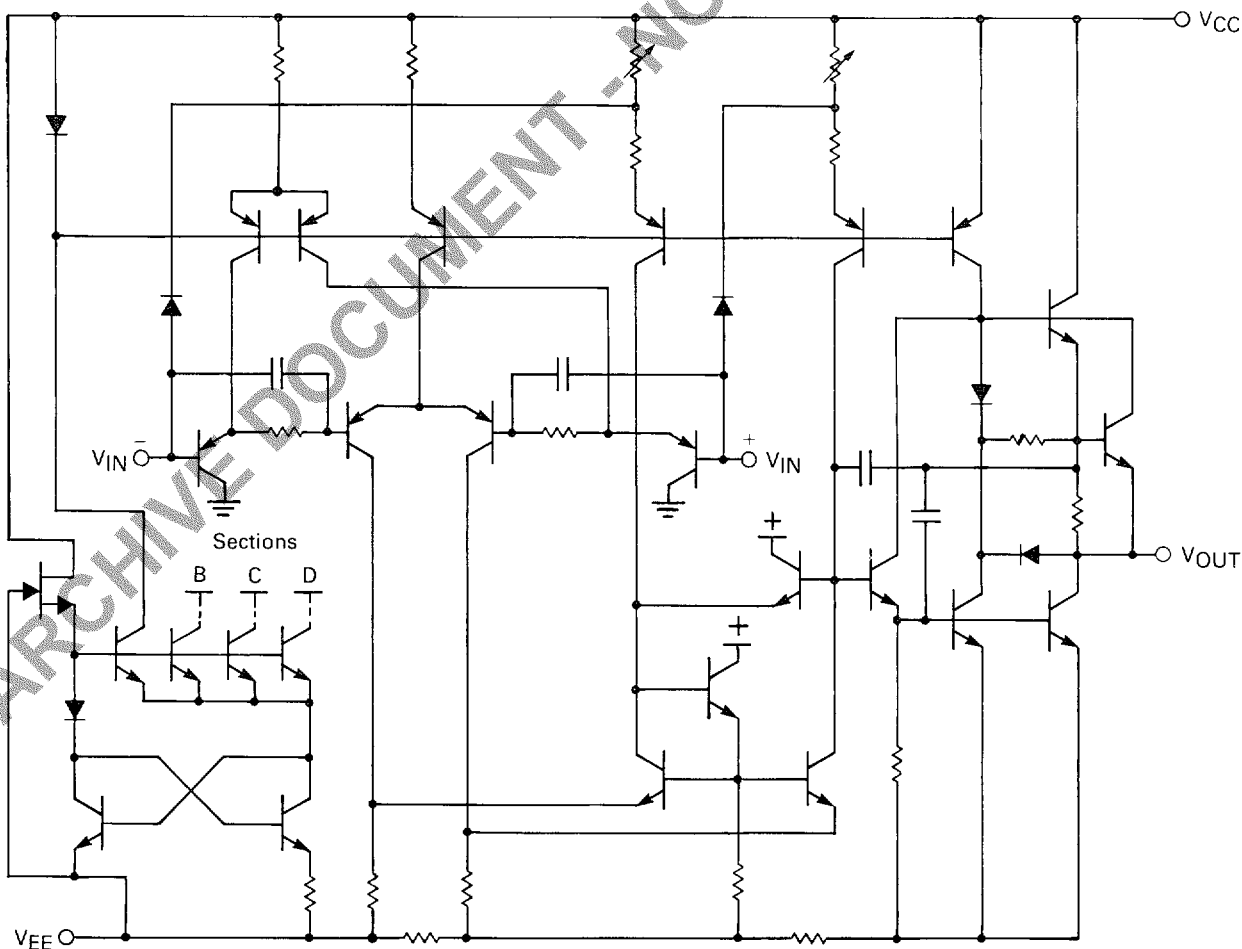


FIGURE 2 — MAXIMUM POWER DISSIPATION versus TEMPERATURE

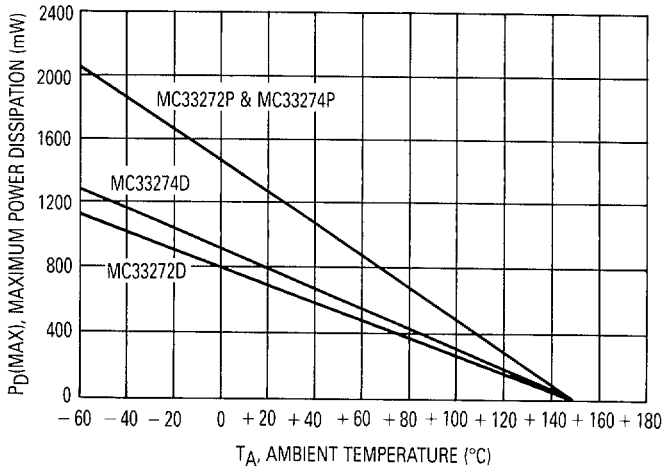


FIGURE 3 — INPUT OFFSET VOLTAGE versus TEMPERATURE FOR TYPICAL UNITS

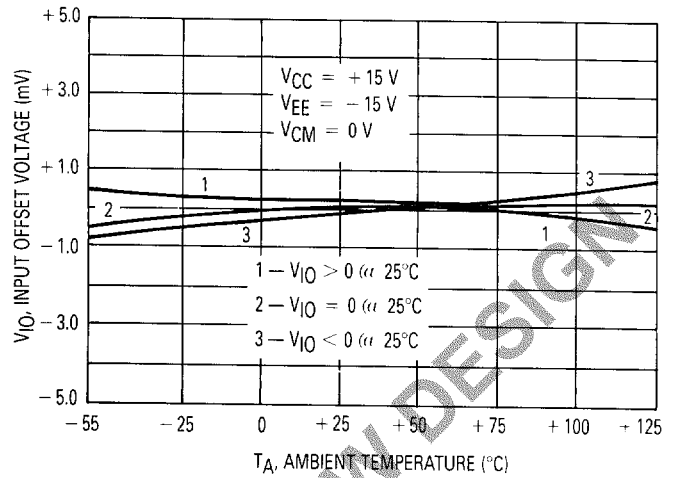


FIGURE 4 — INPUT BIAS CURRENT versus COMMON MODE VOLTAGE

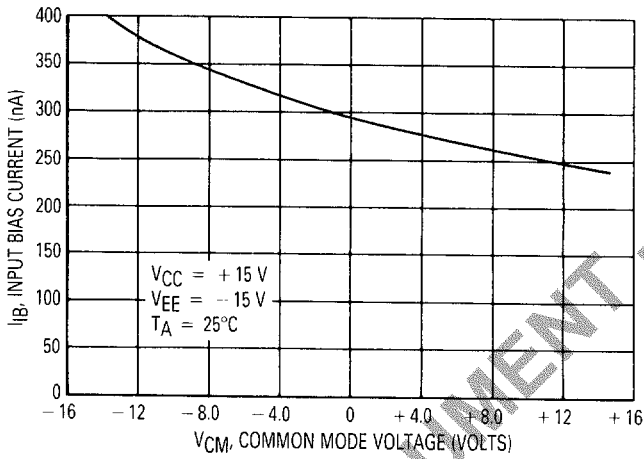


FIGURE 5 — INPUT BIAS CURRENT versus TEMPERATURE

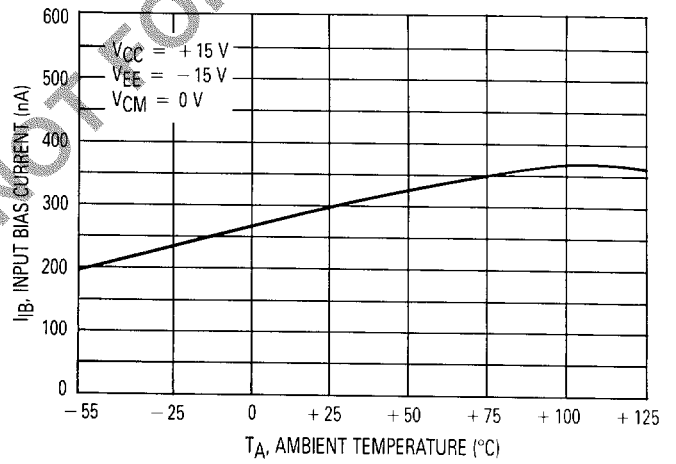


FIGURE 6 — INPUT COMMON MODE VOLTAGE RANGE versus TEMPERATURE

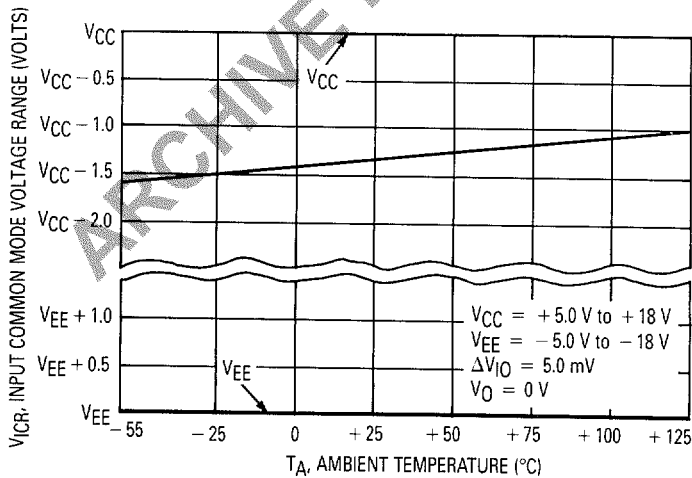


FIGURE 7 — OPEN-LOOP VOLTAGE GAIN versus TEMPERATURE

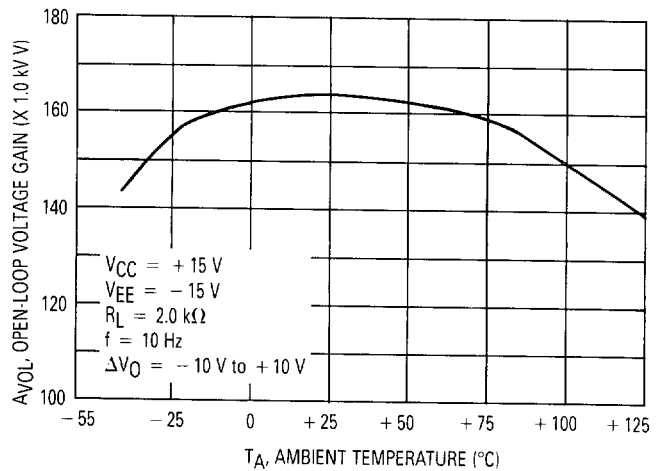


FIGURE 8 — SPLIT SUPPLY OUTPUT VOLTAGE SWING versus SUPPLY VOLTAGE

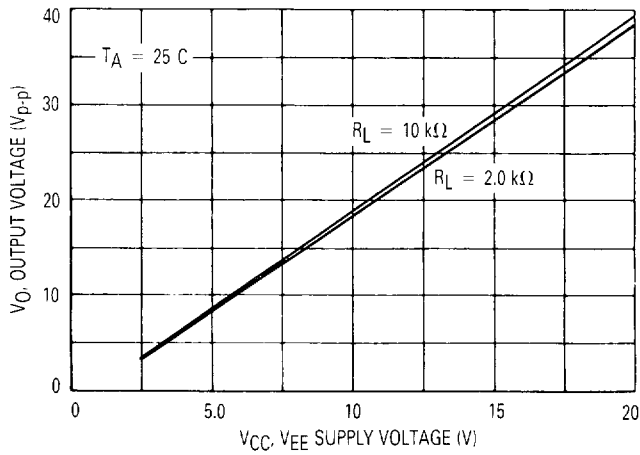


FIGURE 9 — SPLIT SUPPLY OUTPUT SATURATION VOLTAGE versus LOAD CURRENT

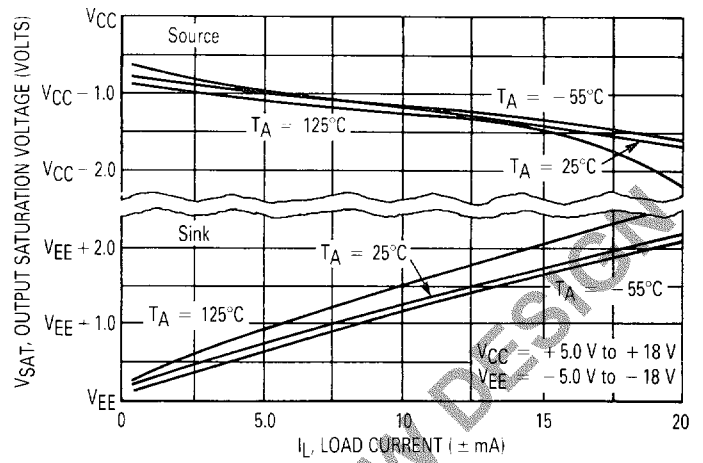


FIGURE 10 — SINGLE SUPPLY OUTPUT SATURATION VOLTAGE versus LOAD RESISTANCE TO GROUND

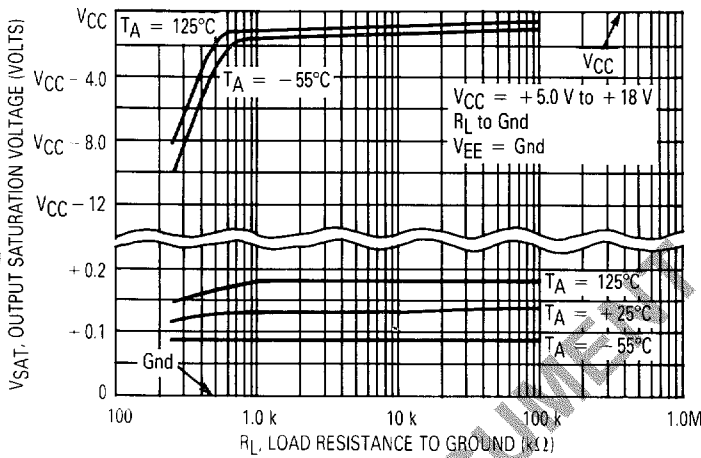


FIGURE 11 — SINGLE SUPPLY OUTPUT SATURATION VOLTAGE versus LOAD RESISTANCE TO V_C.C.

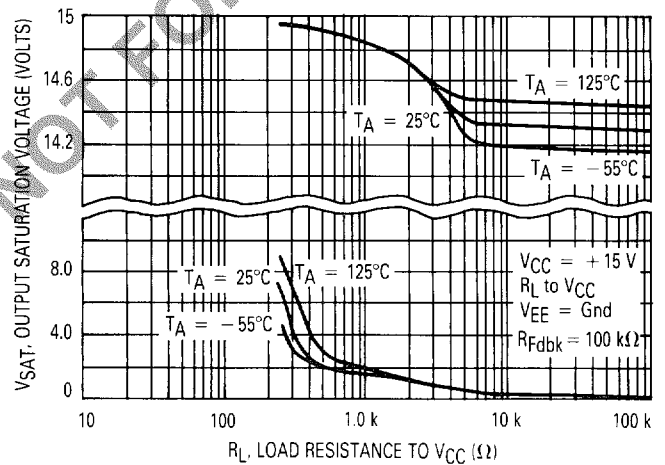


FIGURE 12 — OUTPUT VOLTAGE versus FREQUENCY

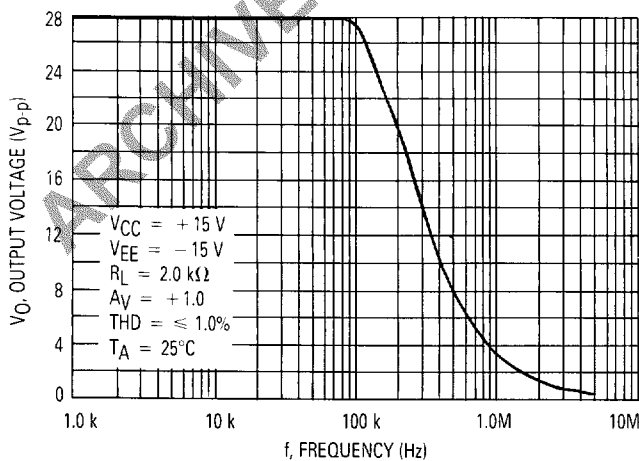
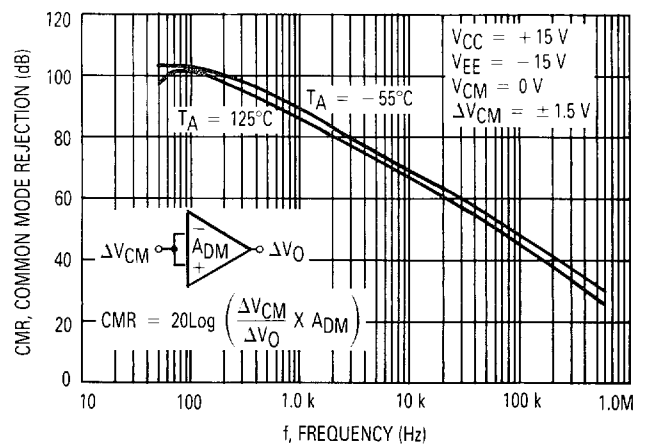
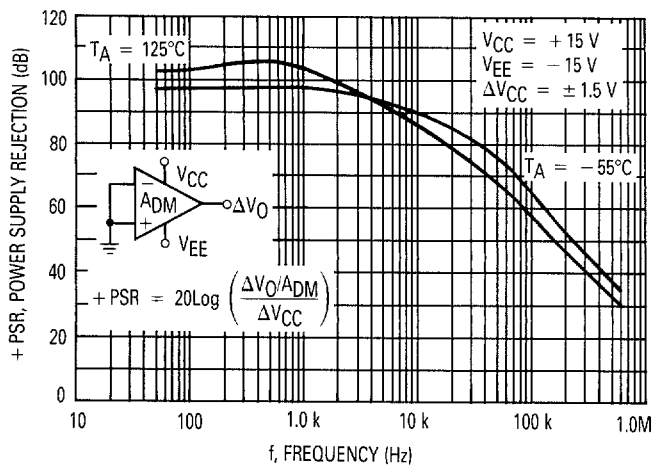


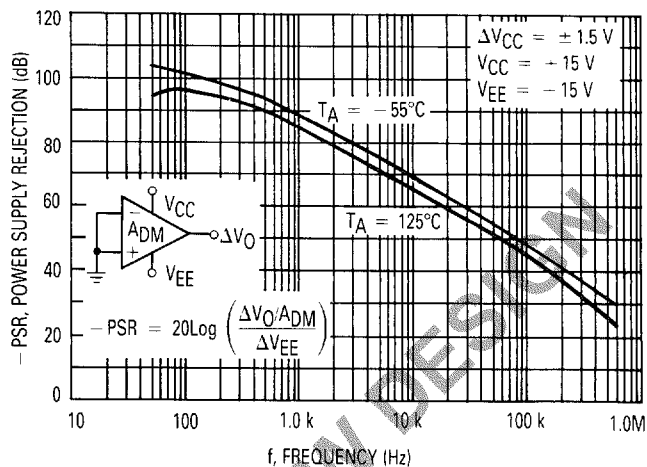
FIGURE 13 — COMMON MODE REJECTION versus FREQUENCY



**FIGURE 14 — POSITIVE POWER SUPPLY REJECTION
versus FREQUENCY**



**FIGURE 15 — NEGATIVE POWER SUPPLY REJECTION
versus FREQUENCY**



**FIGURE 16 — OUTPUT SHORT CIRCUIT CURRENT
versus TEMPERATURE**

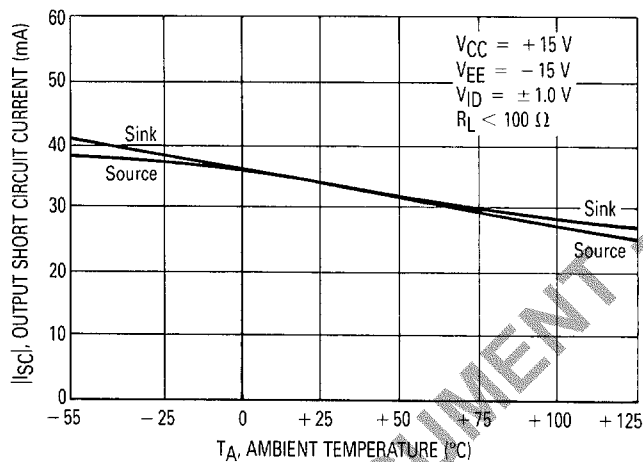
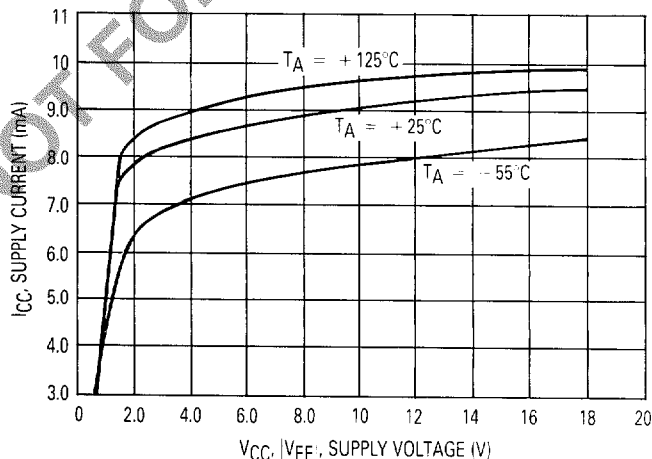
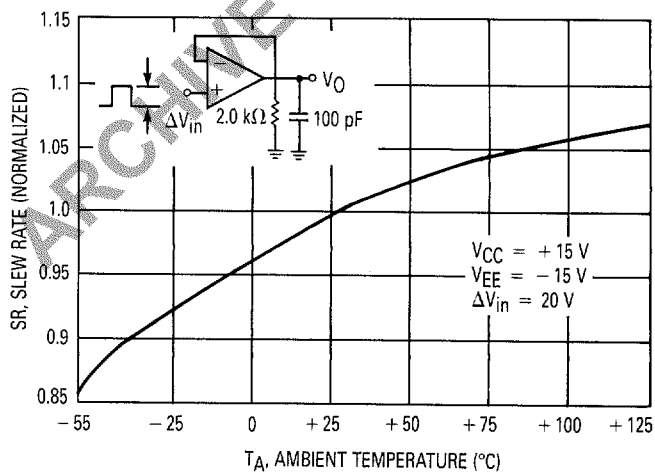


FIGURE 17 — SUPPLY CURRENT versus SUPPLY VOLTAGE



**FIGURE 18 — NORMALIZED SLEW RATE
versus TEMPERATURE**



**FIGURE 19 — GAIN BANDWIDTH PRODUCT
versus TEMPERATURE**

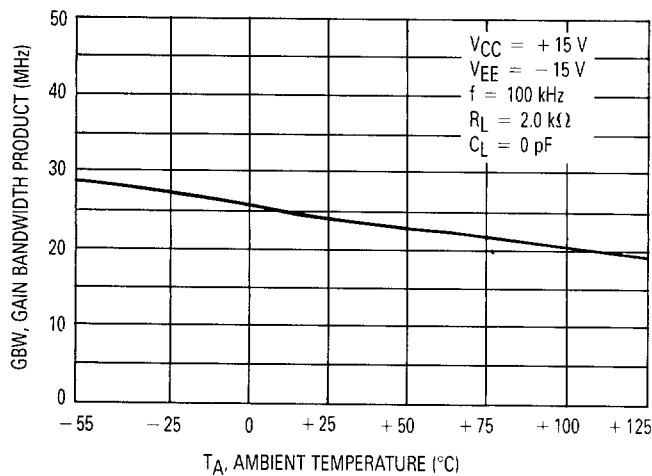


FIGURE 20 — VOLTAGE GAIN & PHASE versus FREQUENCY

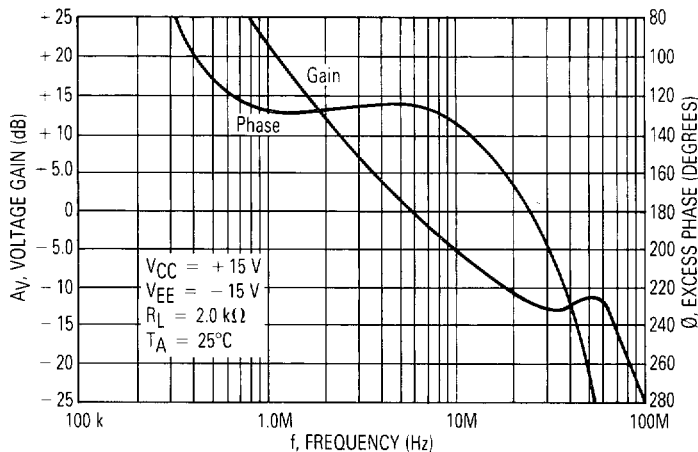


FIGURE 21 — GAIN AND PHASE versus FREQUENCY

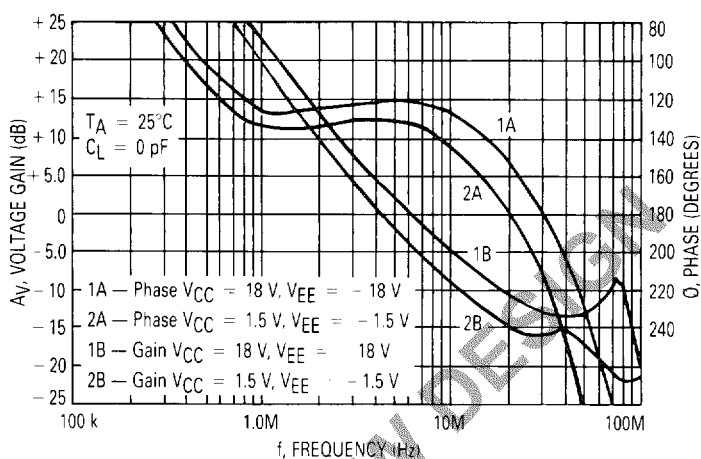


FIGURE 22 — OPEN-LOOP VOLTAGE GAIN & PHASE versus FREQUENCY

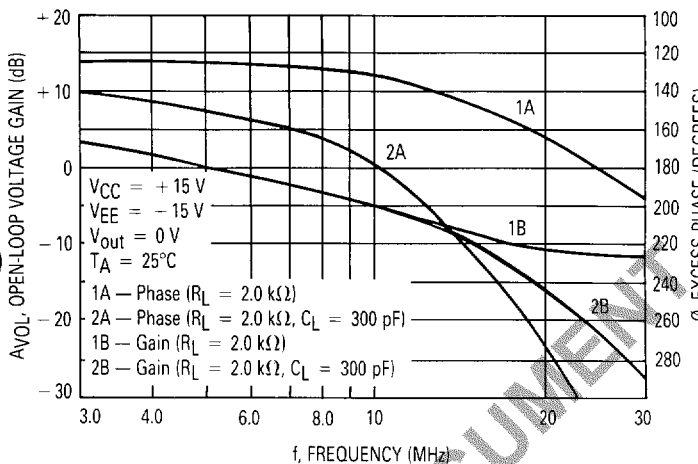


FIGURE 23 — OPEN-LOOP GAIN MARGIN AND PHASE MARGIN versus OUTPUT LOAD CAPACITANCE

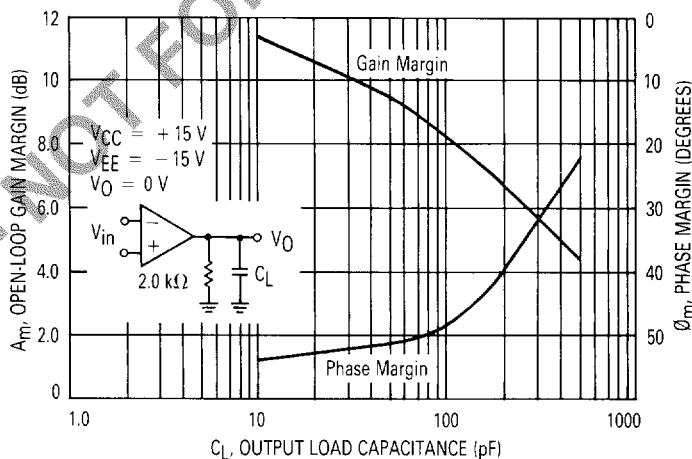


FIGURE 24 — OPEN-LOOP GAIN MARGIN versus TEMPERATURE

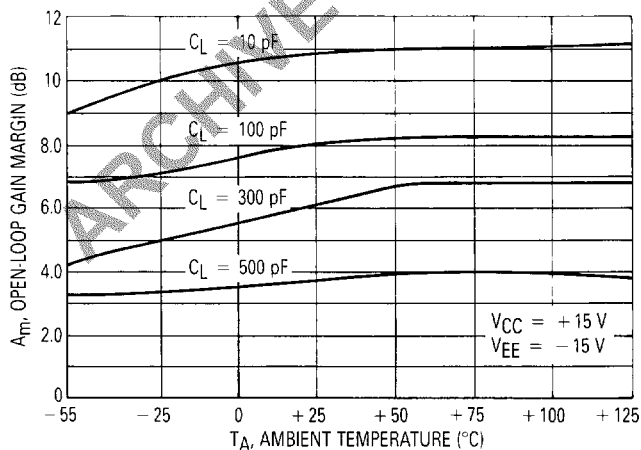


FIGURE 25 — PHASE MARGIN versus TEMPERATURE

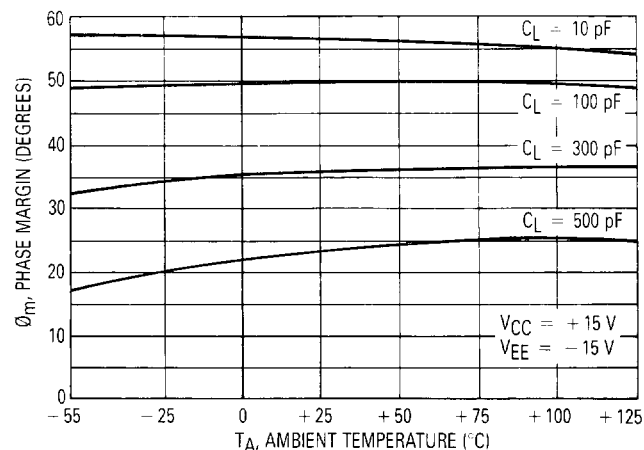


FIGURE 26 — PHASE MARGIN AND GAIN MARGIN versus DIFFERENTIAL SOURCE RESISTANCE

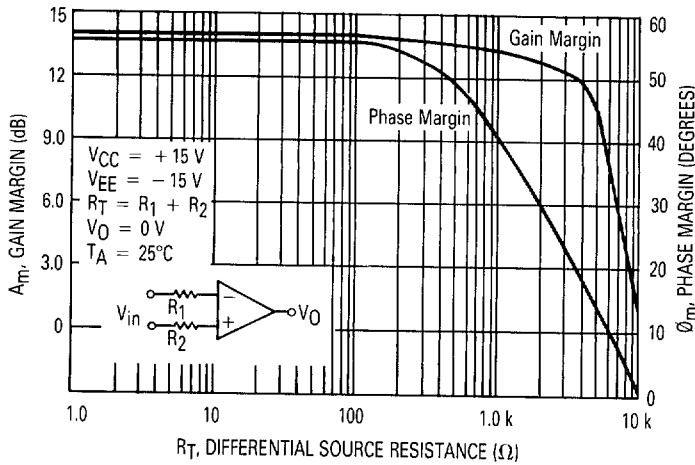


FIGURE 27 — CHANNEL SEPARATION versus FREQUENCY

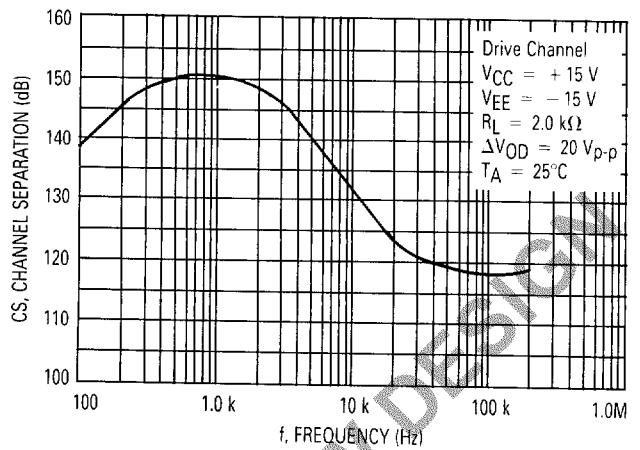


FIGURE 28 — TOTAL HARMONIC DISTORTION versus FREQUENCY

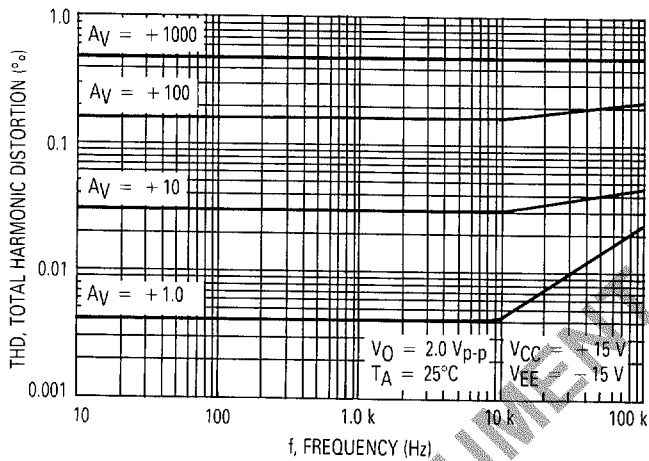


FIGURE 29 — OUTPUT IMPEDANCE versus FREQUENCY

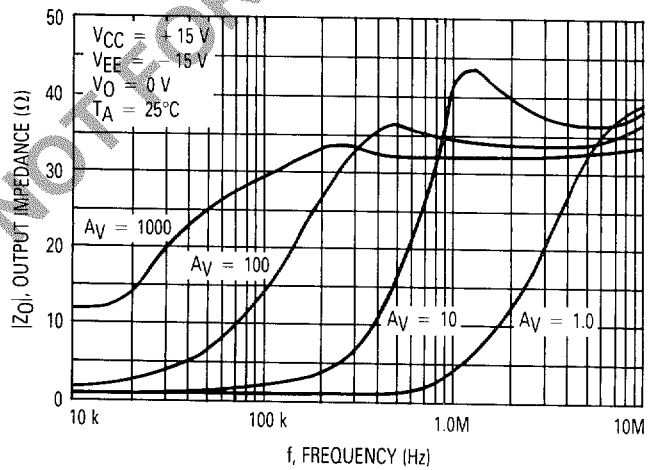


FIGURE 30 — INPUT REFERRED NOISE VOLTAGE versus FREQUENCY

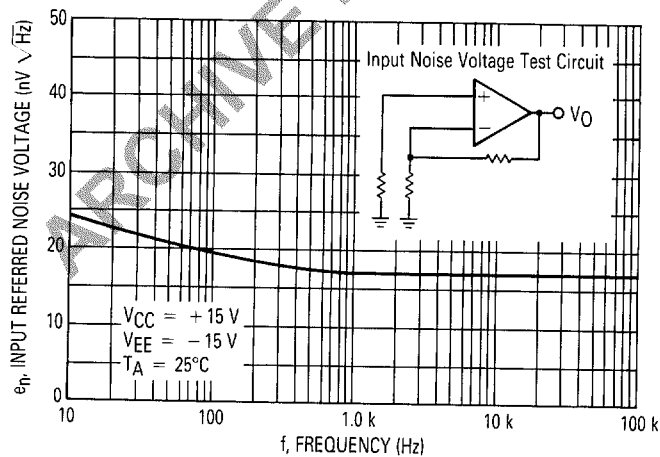


FIGURE 31 — INPUT REFERRED NOISE CURRENT versus FREQUENCY

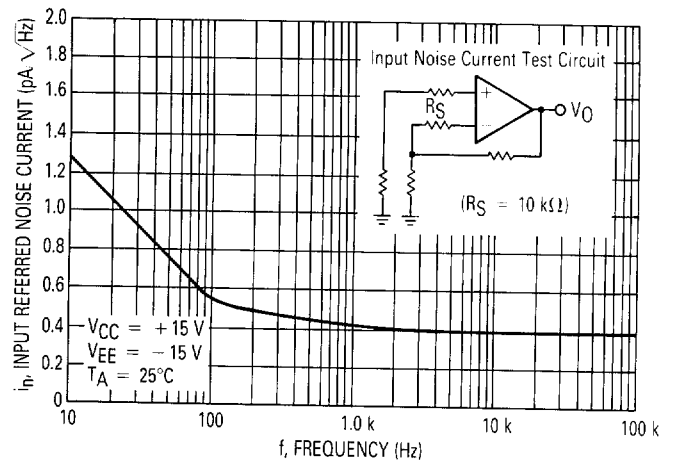


FIGURE 32 — PERCENT OVERSHOOT versus LOAD CAPACITANCE

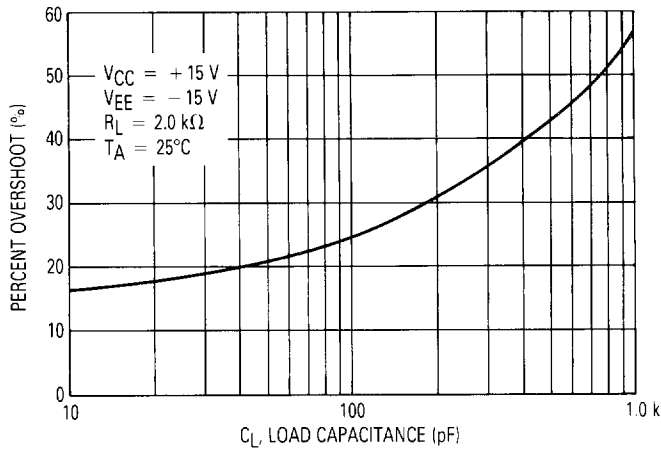


FIGURE 33 — NONINVERTING AMPLIFIER SLEW RATE FOR THE MC33274

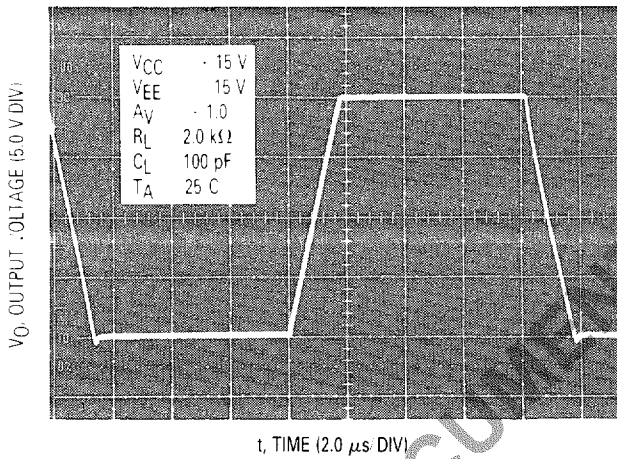


FIGURE 34 — NONINVERTING AMPLIFIER OVERSHOOT FOR THE MC33274

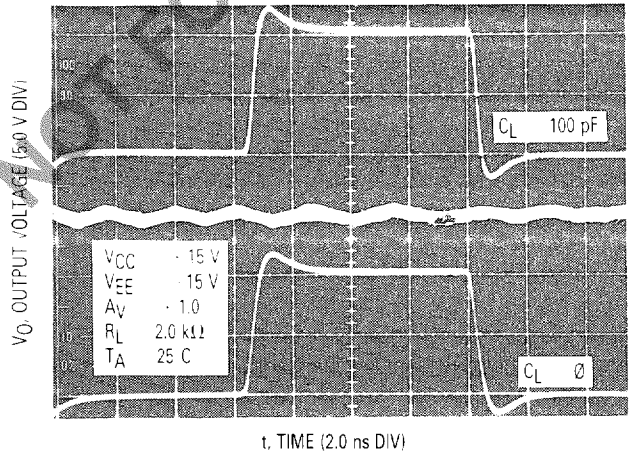


FIGURE 35 — SMALL SIGNAL TRANSIENT RESPONSE FOR MC33274

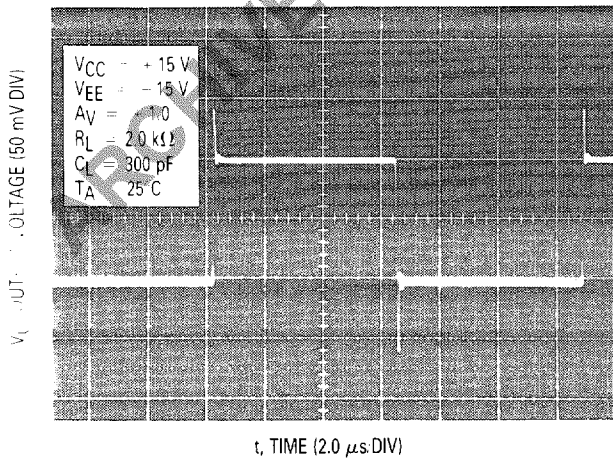
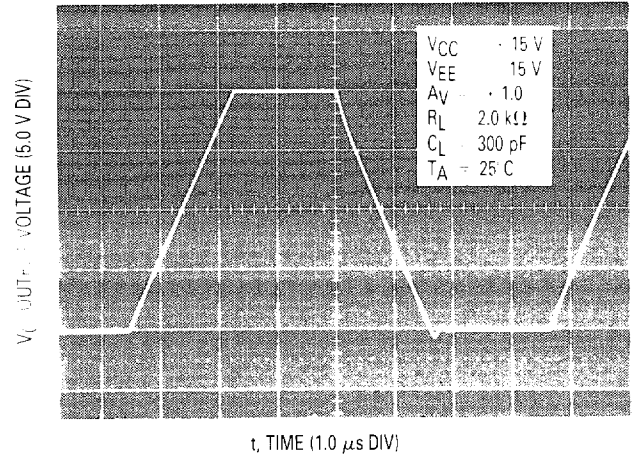
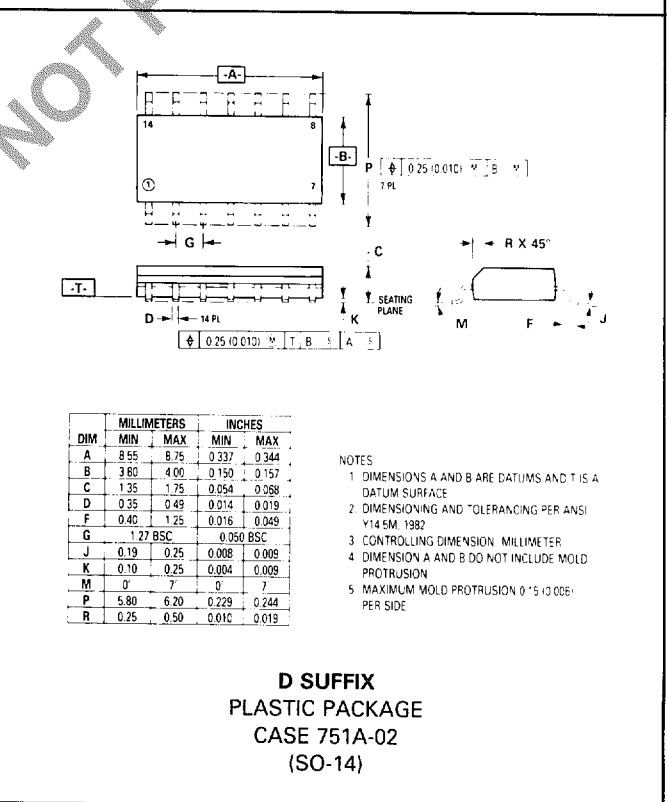
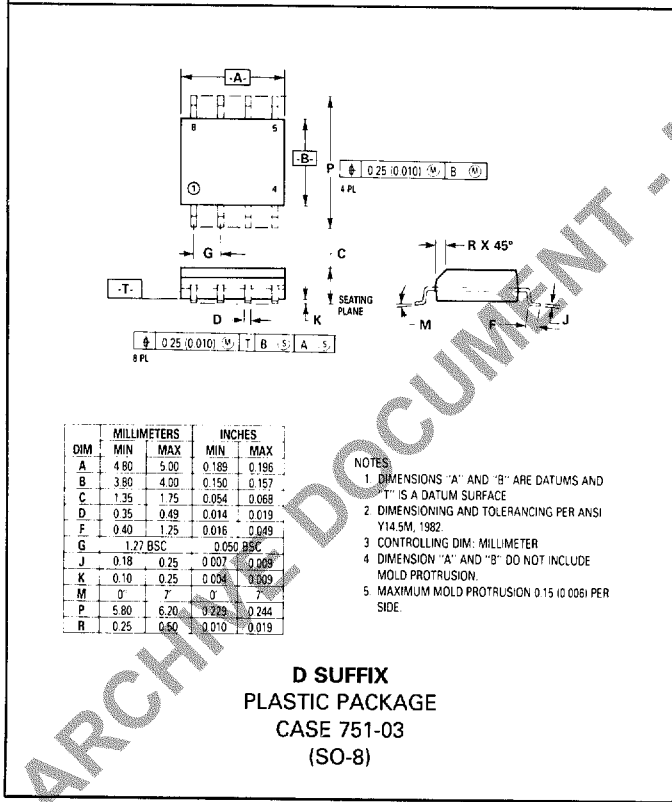
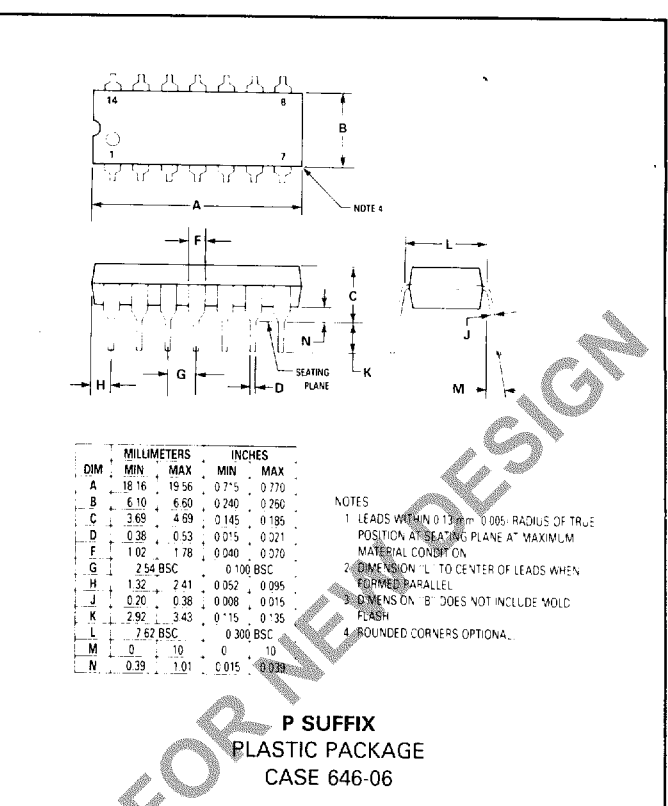
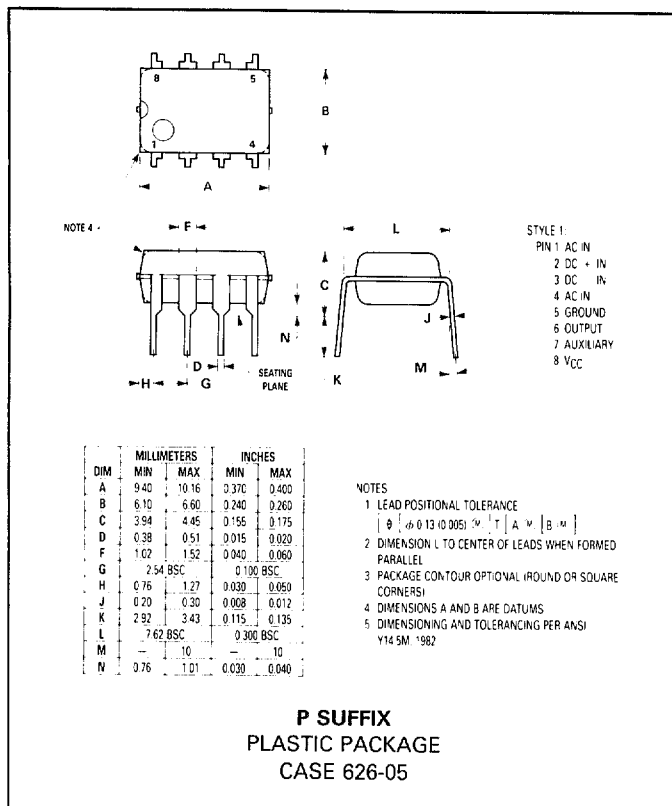


FIGURE 36 — LARGE SIGNAL TRANSIENT RESPONSE FOR MC33274



OUTLINE DIMENSIONS



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